

**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****General Description**

The AP4310 is a monolithic IC specifically designed to regulate the output current and voltage levels of switching battery chargers and power supplies.

The device contains two Op Amps and a 2.5V precision shunt voltage reference. Op Amp 1 is designed for voltage control with its non-inverting input internally connects to the output of the shunt regulator. Op Amp 2 is for current control with both inputs uncommitted. The IC offers the power converter designer a control solution that features increased precision with a corresponding reduction in system complexity and cost.

The AP4310 is available in standard packages of DIP-8 and SOIC-8.

Features**Op Amp**

- Input Offset Voltage: 0.5mV
- Supply Current: 75 μ A per Op Amp at 5.0V Supply Voltage
- Unity Gain Bandwidth: 1MHz
- Output Voltage Swing: 0 to ($V_{CC} - 1.5$) V
- Power Supply Range: 3 to 36V

Voltage Reference

- Fixed Output Voltage Reference: 2.5V
- Voltage Tolerance: $\pm 0.4\%$, $\pm 1\%$
- Sink Current Capability: 0.05 to 80mA
- Typical Output Impedance: 0.2 Ω

Applications

- Battery Charger
- Switching Power Supply

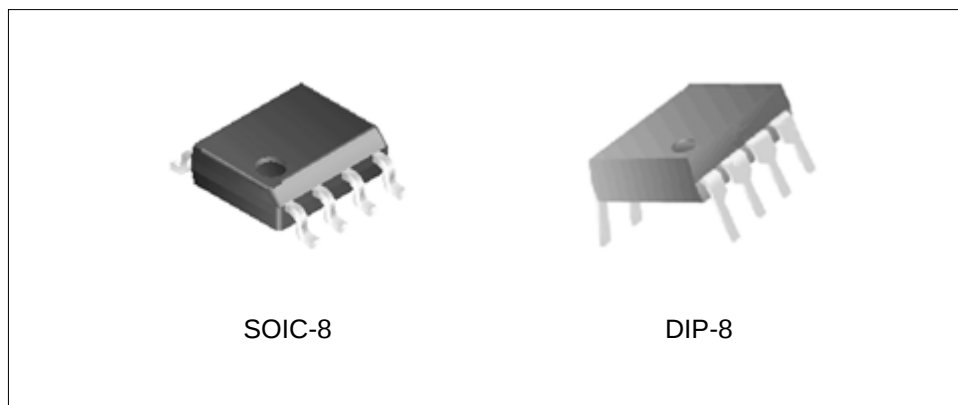


Figure 1. Package Types of AP4310

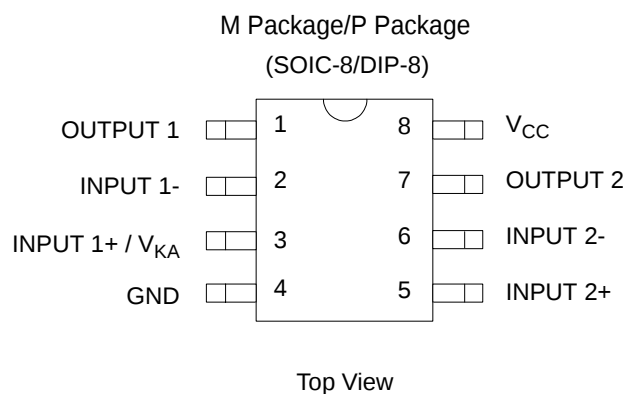
**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****Pin Configuration**

Figure 2. Pin Configuration of AP4310

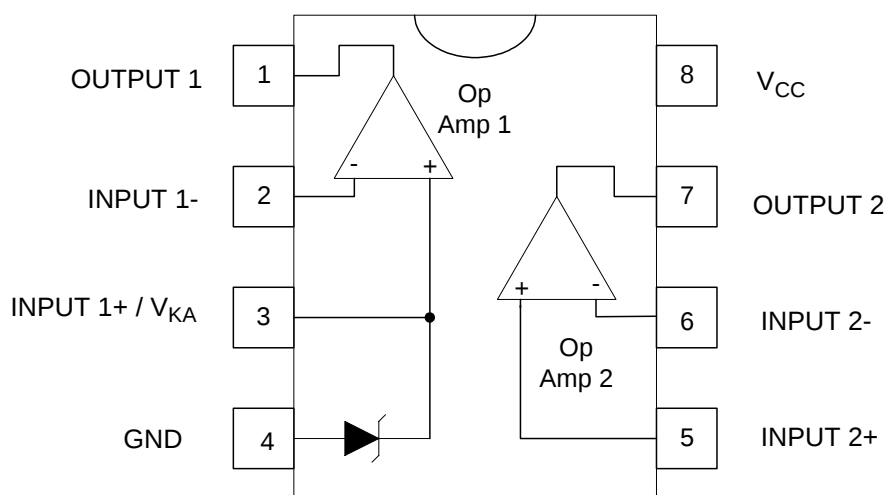
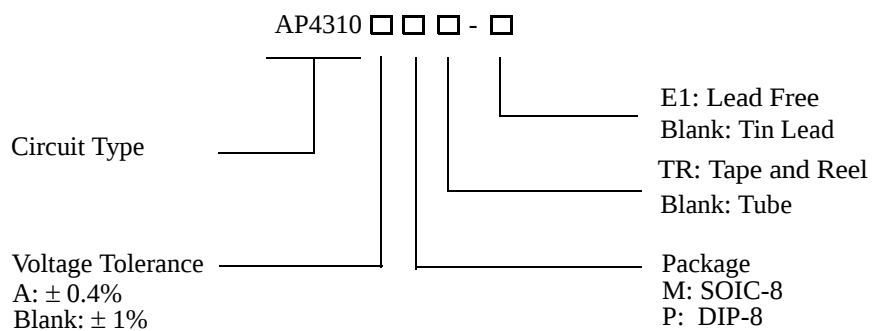
Functional Block Diagram

Figure 3. Functional Block Diagram of AP4310

**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****Ordering Information**

Package	Reference Voltage	Voltage Tolerance	Temperature Range	Part Number		Marking ID		Packing Type
				Tin Lead	Lead Free	Tin Lead	Lead Free	
DIP-8	2.5V	$\pm 0.4\%$	-40 to105°C	AP4310AP	AP4310AP-E1	AP4310AP	AP4310AP-E1	Tube
		$\pm 1\%$		AP4310P	AP4310P-E1	AP4310P	AP4310P-E1	
SOIC-8	2.5V	$\pm 0.4\%$	-40 to105°C	AP4310AM	AP4310AM-E1	4310AM	AP4310AM-E1	Tube
				AP4310AMTR	AP4310AMTR-E1	4310AM	AP4310AM-E1	Tape & Reel
		$\pm 1\%$	-40 to105°C	AP4310M	AP4310M-E1	4310M	AP4310M-E1	Tube
				AP4310MTR	AP4310MTR-E1	4310M	AP4310M-E1	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Power Supply Voltage (V_{CC} to GND)	V_{CC}	40		V
Op Amp 1 and 2 Input Voltage Range (Pins 2, 5, 6)	V_{IN}	-0.3 to $V_{CC}+0.3$		V
Op Amp 2 Input Differential Voltage (Pins 5, 6)	V_{ID}	40		V
Voltage Reference Cathode Current (Pin 3)	I_K	100		mA
Power Dissipation ($T_A=25^{\circ}\text{C}$)	P_D	DIP-8	800	mW
		SOIC-8	500	
Operating Junction Temperature	T_J	150		$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to 150		$^{\circ}\text{C}$
Lead Temperature (Soldering 10s)	T_{LEAD}	260		$^{\circ}\text{C}$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Min	Max	Unit
Supply Voltage	3	36	V
Ambient Temperature	-40	105	$^{\circ}\text{C}$



DUAL OP AMP AND VOLTAGE REFERENCE

AP4310

Electrical Characteristics

Operating Conditions: $V_{CC} = +5V$, $T_A = 25^\circ C$ unless otherwise specified.

Parameter		Conditions		Min	Typ	Max	Unit
Total Supply Current, excluding Current in Voltage Reference		V _{CC} =5V, no load, -40°C≤T _A ≤105°C			0.15	0.25	mA
		V _{CC} =30V, no load, -40°C≤T _A ≤105°C			0.20	0.30	
Voltage Reference Section							
Reference Voltage	AP4310A	I _K =10mA	T _A =25°C	2.49	2.50	2.51	V
			-40°C≤T _A ≤105°C	2.48	2.50	2.52	
	AP4310		T _A =25°C	2.475	2.50	2.525	V
			-40°C≤T _A ≤105°C	2.45	2.50	2.55	
Reference Voltage Deviation Over Full Temperature Range		I _K =10mA, T _A =-40 to 105°C			5	24	mV
Minimum Cathode Current for Regulation					0.01	0.05	mA
Dynamic Impedance		I _K =1.0 to 80mA, f<1kHz			0.2	0.5	Ω
Op Amp 1 Section (V _{CC} =5V, V _O =1.4V, T _A =25°C, unless otherwise noted)							
Input Offset Voltage		T _A =25°C			0.5	3	mV
		T _A =-40 to 105°C				5	
Input Offset Voltage Temperature Drift		T _A =-40 to 105°C			7		μV/°C
Input Bias Current (Inverting Input Only)		T _A =25°C			20	150	nA
Large Signal Voltage Gain		V _{CC} =15V, R _L =2kΩ, V _O =1.4 to 11.4V		85	100		dB
Power Supply Rejection Ratio		V _{CC} =5 to 30V		70	90		dB
Output Current	Source	V _{CC} =15V, V _{ID} =1V, V _O =2V		20	40		mA
	Sink	V _{CC} =15V, V _{ID} =-1V, V _O =2V		7	20		mA
Output Voltage Swing (High)		V _{CC} =30V, R _L =10kΩ, V _{ID} =1V		27	28		V
Output Voltage Swing (Low)		V _{CC} =30V, R _L =10kΩ, V _{ID} =-1V			17	100	mV
Slew Rate		V _{CC} =18V, R _L =2kΩ, A _V =1, V _{IN} =0.5 to 2V, C _L =100pF		0.2	0.5		V/μ s
Unity Gain Bandwidth		V _{CC} =30V, R _L =2kΩ, C _L =100pF		0.7	1.0		MHz



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Electrical Characteristics (Continued)

Operating Conditions: $V_{CC}=+5V$, $T_A=25^{\circ}C$ unless otherwise specified.

Parameter	Conditions	Min	Typ	Max	Unit
Op Amp 2 Section ($V_{CC}=5V$, $V_O=1.4V$, $T_A=25^{\circ}C$, unless otherwise noted)					
Input Offset Voltage	$T_A=25^{\circ}C$		0.5	3	mV
	$T_A=-40$ to $105^{\circ}C$			5	
Input Offset Voltage Temperature Drift	$T_A=-40$ to $105^{\circ}C$		7		$\mu V/^{\circ}C$
Input Offset Current	$T_A=25^{\circ}C$		2	30	nA
Input Bias Current	$T_A=25^{\circ}C$		20	150	nA
Input Voltage Range	$V_{CC}=0$ to $36V$	0		$V_{CC}-1.5$	V
Common Mode Rejection Ratio	$T_A=25^{\circ}C$, $V_{CM}=0$ to $3.5V$	70	85		dB
Large Signal Voltage Gain	$V_{CC}=15V$, $R_L=2k\Omega$, $V_O=1.4$ to $11.4V$	85	100		dB
Power Supply Rejection Ratio	$V_{CC}=5$ to $30V$	70	90		dB
Output Current	Source	$V_{CC}=15V$, $V_{ID}=1V$, $V_O=2V$	20	40	mA
	Sink	$V_{CC}=15V$, $V_{ID}=-1V$, $V_O=2V$	7	20	mA
Output Voltage Swing (High)	$V_{CC}=30V$, $R_L=10k\Omega$, $V_{ID}=1V$	27	28		V
Output Voltage Swing (Low)	$V_{CC}=30V$, $R_L=10k\Omega$, $V_{ID}=-1V$		17	100	mV
Slew Rate	$V_{CC}=18V$, $R_L=2k\Omega$, $A_V=1$, $V_{IN}=0.5$ to $2V$, $C_L=100pF$	0.2	0.5		$V/\mu s$
Unity Gain Bandwidth	$V_{CC}=30V$, $R_L=2k\Omega$, $C_L=100pF$	0.7	1.0		MHz



DUAL OP AMP AND VOLTAGE REFERENCE

AP4310

Typical Performance Characteristics

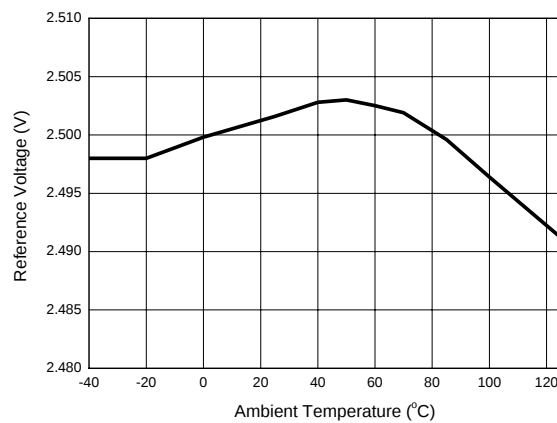


Figure 4. Reference Voltage vs. Ambient Temperature

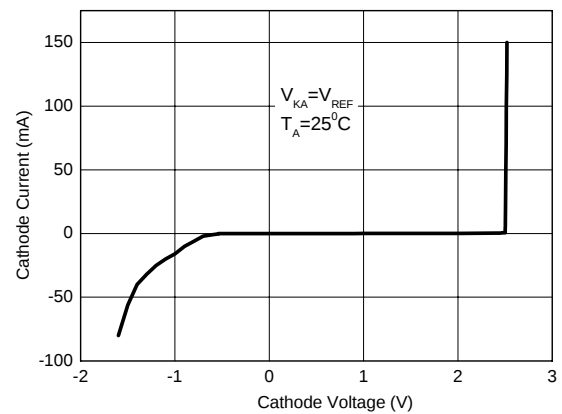


Figure 5. Cathode Current vs. Cathode Voltage

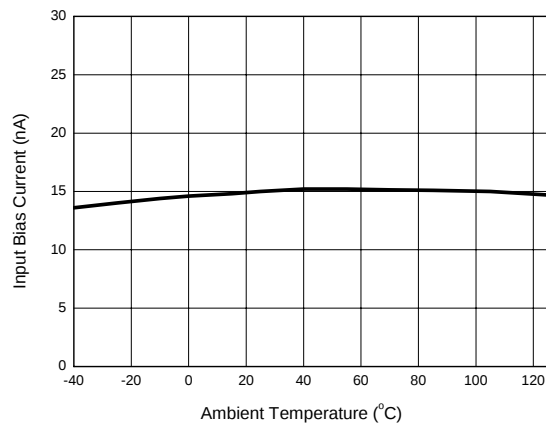


Figure 6. Input Bias Current vs. Ambient Temperature

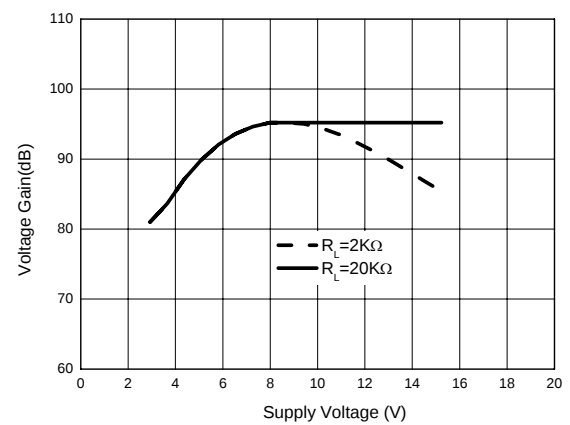


Figure 7. Op Amp Voltage Gain

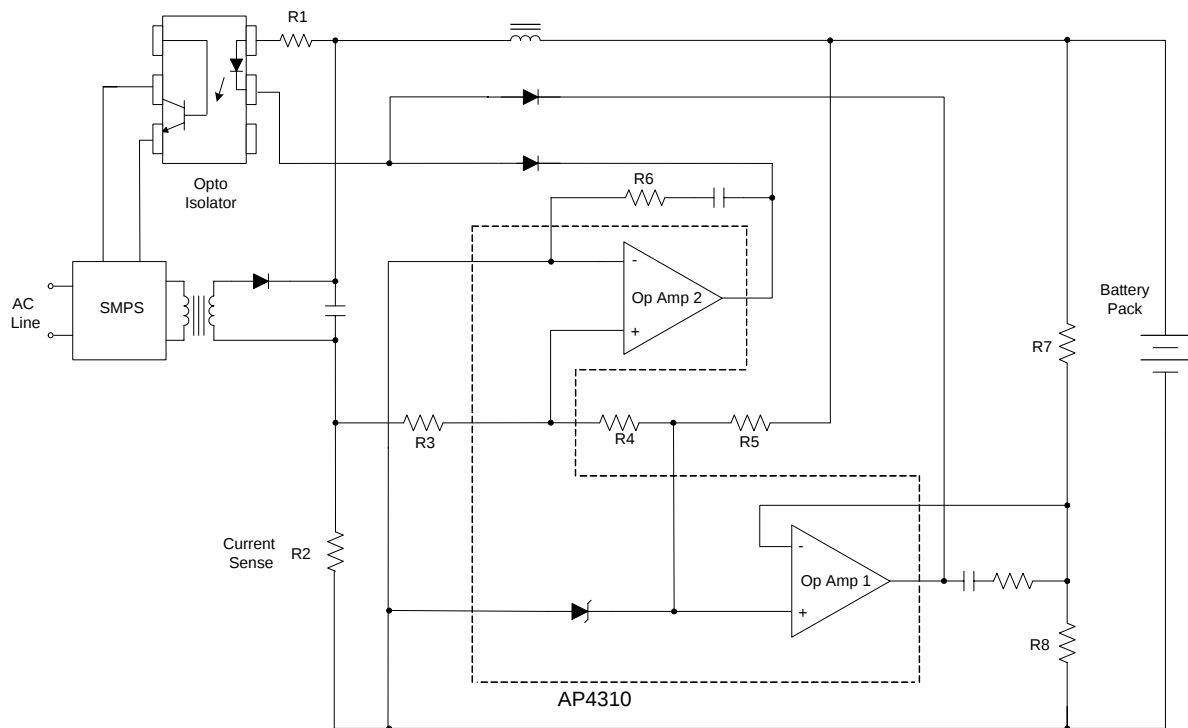
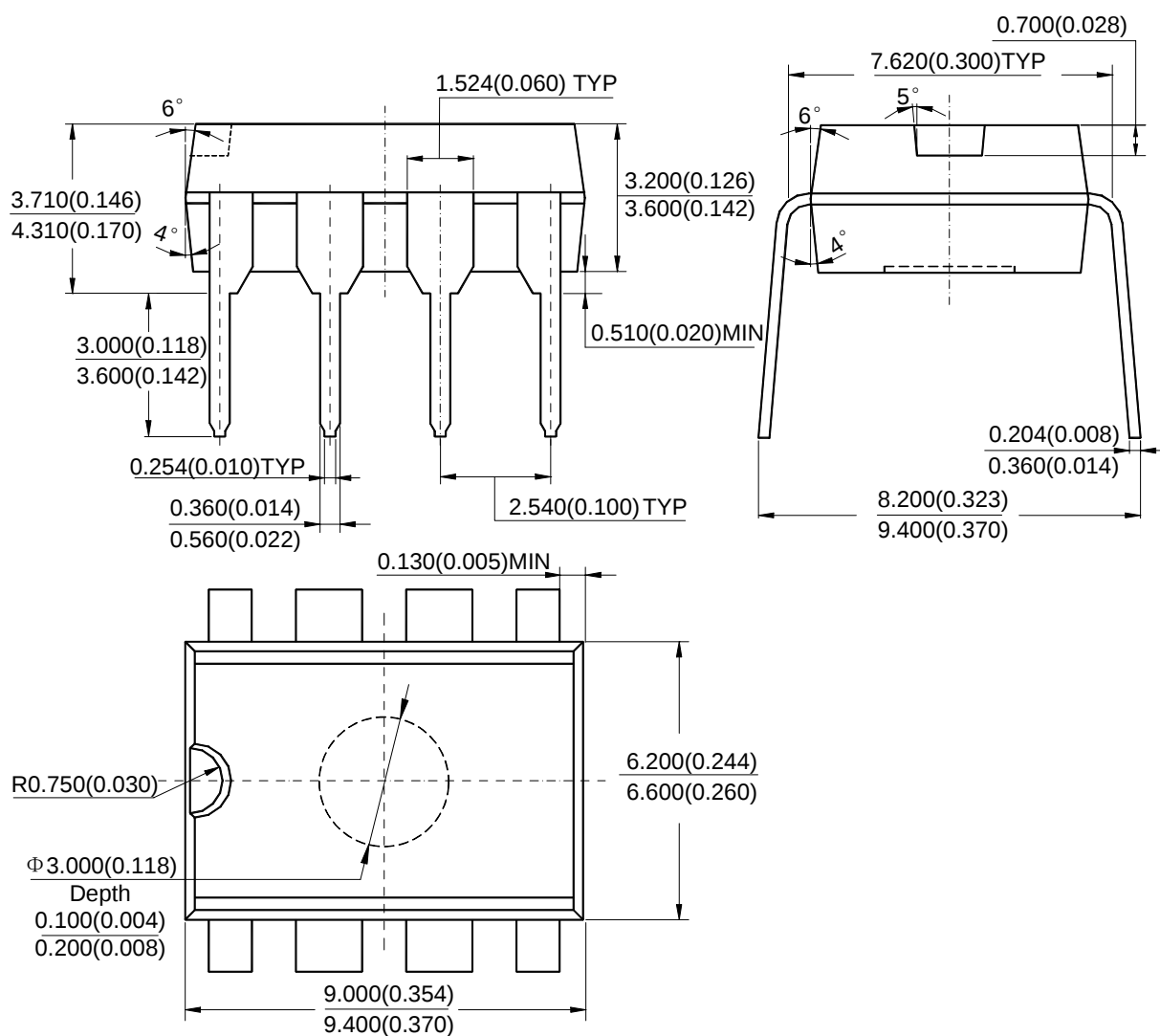
**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****Typical Application**

Figure 8. Application of AP4310 in a Constant Current and Constant Voltage Charger

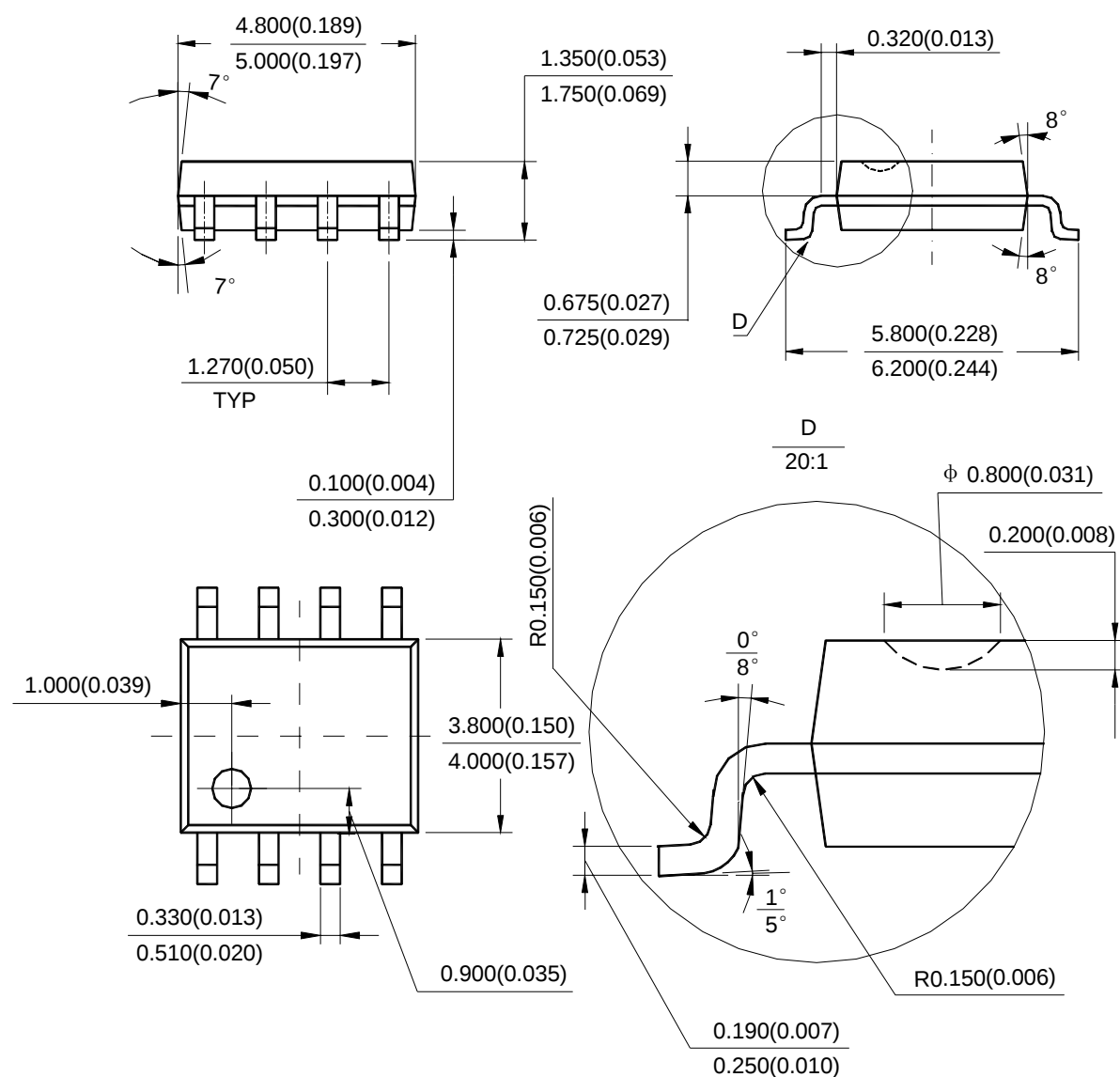
**DUAL OP AMP AND VOLTAGE REFERENCE****AP4310****Mechanical Dimensions:****DIP-8****Unit: mm(inch)**



Mechanical Dimensions (Continued):

SOIC-8

Unit: mm(inch)





BCD Semiconductor Manufacturing Limited

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